



**SOT-23 Plastic-Encapsulate Transistors**

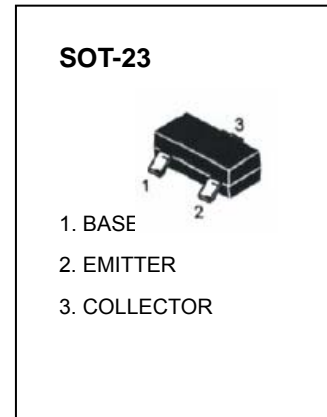
**2SA1037** TRANSISTOR (PNP)

**FEATURES**

- Excellent  $h_{FE}$  linearity.
- Compliments the 2SC2412

**MARKING : FQ, FR, FS**

**MAXIMUM RATINGS ( $T_A=25^{\circ}\text{C}$  unless otherwise noted)**



Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	-60	V
$V_{CEO}$	Collector-Emitter Voltage	-50	V
$V_{EBO}$	Emitter-Base Voltage	-6	V
$I_C$	Collector Current -Continuous	150	mA
$P_C$	Collector Power Dissipation	200	mW
$T_J$	Junction Temperature	150	$^{\circ}\text{C}$
$T_{stg}$	Storage Temperature	-55-150	$^{\circ}\text{C}$

**ELECTRICAL CHARACTERISTICS ( $T_{amb}=25^{\circ}\text{C}$  unless otherwise specified)**

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=-50\mu\text{A}, I_E=0$	-60			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=-1\text{mA}, I_B=0$	-50			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=-50\mu\text{A}, I_C=0$	-6			V
Collector cut-off current	$I_{CBO}$	$V_{CB}=-60\text{V}, I_E=0$			-0.1	$\mu\text{A}$
Emitter cut-off current	$I_{EBO}$	$V_{EB}=-6\text{V}, I_C=0$			-0.1	$\mu\text{A}$
DC current gain	$h_{FE}$	$V_{CE}=-6\text{V}, I_C=-1\text{mA}$	120		560	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=-50\text{mA}, I_B=-5\text{mA}$			-0.5	V
Transition frequency	$f_T$	$V_{CE}=-12\text{V}, I_C=-2\text{mA}, f=30\text{MHz}$		140		MHz
Collector output capacitance	$C_{ob}$	$V_{CB}=-12\text{V}, I_E=0, f=1\text{MHz}$		4.0	5.0	pF

**CLASSIFICATION OF  $h_{FE}$**

Rank	Q	R	S
Range	120 - 270	180 - 390	270 - 560